

Monolithic Linear IC

# LA6542M

## 4-Channel Bridge (BTL) Driver for CD-ROM

### **Overview**

The LA6542M is a 4-channel bridge (BTL) driver developed for CD-ROM applications.

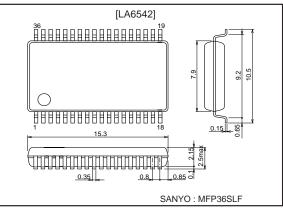
### **Functions**

- 4-channel power amplifier with bridge circuit (BTL)
- I<sub>o</sub>max: 1A
- Integrated muting circuit (MUTE: Output OFF at Low, output ON at High. MUTE1 is for channels 1 and 2, and MUTE2 for channels 3 and 4.)
- Slew rate 0.5 V/µs
- Integrated thermal shutdown circuit

### **Package Dimensions**

unit: mm

### 3204-MFP36SLF



### **Specifications**

#### Maximum Ratings at $Ta = 25^{\circ}C$

•				
Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage 1	V <sub>CC</sub> max		14	V
Maximum supply voltage 2	V <sub>S</sub> max	V <sub>S</sub> 1, 2	14	V
Maximum input voltage	V <sub>IN</sub> max	Input pins $V_{IN}$ 1 to 4	13	V
Mute pin voltage	V <sub>MUTE</sub> max		13	V
Allowable power dissipation	Pd max	IC only	0.9	W
Operating temperature	Topr		-20 to +75	°C
Storage temperature	Tstg		-55 to +150	°C

### Operating Conditions at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Recommended operation voltage 1	V <sub>CC</sub>		4 to 13	V
Recommended operation voltage 2-1	V <sub>S</sub> 1		4 to 13	V
Recommended operation voltage 2-2	V <sub>S</sub> 2		4 to 13	V

 $^*V_{CC} \ge V_S 1, 2$ 

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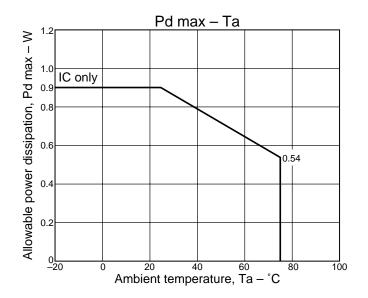
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Demonster	Symbol	Conditions	Ratings			
Parameter			min	typ	max	Unit
V <sub>CC</sub> no-load current drain	I <sub>CC</sub> 1	All outputs ON (MUTE1, MUTE2: High)	5	10	20	mA
	I <sub>CC</sub> 2	All outputs OFF (MUTE1, MUTE2: Low)		5	10	mA
V <sub>S</sub> 1 no-load current drain	I <sub>S</sub> 1-1	CH1, 2 ON (MUTE1, MUTE2: High)		10	30	mA
	I <sub>S</sub> 1-2	CH1, 2 OFF (MUTE1, MUTE2: Low)			4	mA
V <sub>S</sub> 2 no-load current drain	I <sub>S</sub> 2-1	CH3, 4 ON (MUTE1, MUTE2: High)		10	30	mA
	I <sub>S</sub> 2-2	CH3, 4 OFF (MUTE1, MUTE2: Low)			4	mA
Output offset voltage	$V_{\mbox{\scriptsize OF}} 1$ to $4$	Potential difference between plus and minus outputs for CH1 to CH4	-50		50	mV
Input voltage range	V <sub>IN</sub>	Input voltage range for V <sub>IN</sub> 1 to V <sub>IN</sub> 4	0.5		5	V
Output voltage (source)	Vsource	Plus and minus outputs at high level	4.4	4.7		V
		I <sub>O</sub> = 700 mA				
(sink)	Vsink	Plus and minus outputs at low level		0.3	0.6	V
		I <sub>O</sub> = 700 mA				
Closed circuit voltage gain	VG	Voltage gain between BTL amplifiers		6		dB
Slew rate	SR	(Note 1)		0.5		V/µs
Mute ON voltage	V <sub>MUTE</sub>	MUTE1, MUTE2 voltage when output is ON (Note 2)		1.5	2	V
Mute ON current	I <sub>MUTE</sub>	MUTE1, MUTE2 current when output is ON (Note 2)		6	10	μΑ

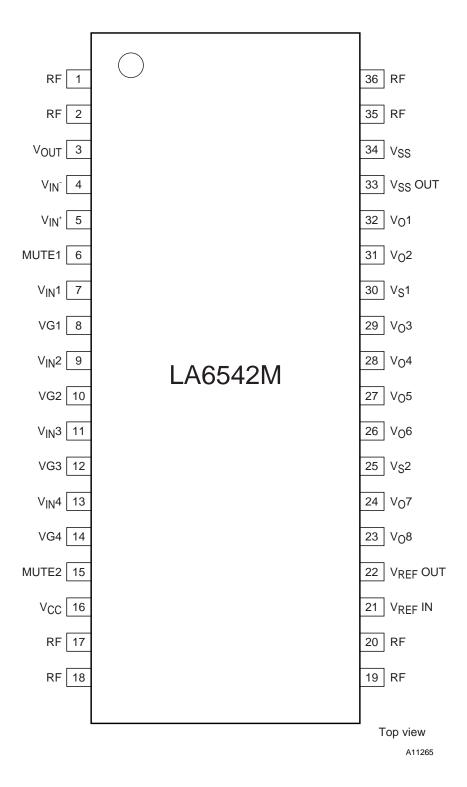
### Electrical Characteristics at $V_{CC}$ = 12V, $\,V_S$ = 5V, Ta = 25 $^\circ C$

Note 1: Guaranteed design value

Note 2: MUTE works on all channels. At High, amplifier output is ON and at Low amplifier output is OFF (output impedance becomes HI).



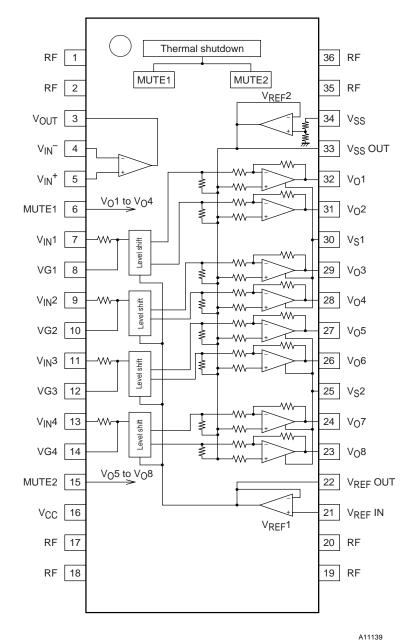
### **Pin Assignment**



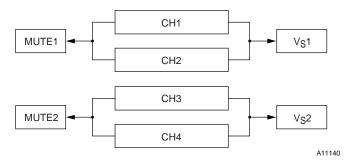
### **Pin Function**

Pin number	Pin name	Equivalent circuit	Pin function
1, 2 17, 18 19, 20 35, 36 7, 9 11, 13 8, 10 12, 14 16 22	R F V <sub>IN</sub> 1, V <sub>IN</sub> 2 V <sub>IN</sub> 3, V <sub>IN</sub> 4 VG1, VG2 VG3, VG4 V <sub>CC</sub> V <sub>REF</sub> OUT	$\begin{array}{c} & & & \\ \hline 0 & V_{\text{IN}} \\ \hline 117 \\ \hline 128 \\ \hline 128 \\ \hline 128 \\ \hline 128 \\ \hline V_{\text{REF}} \text{OUT} \\ \hline 203538 \\ \hline 1136 \\ \hline \end{array}$	Substrate (minimum potential) Input pins for CH1 and CH2 Input pins for CH3 and CH4 Input pins for CH3 and CH4 (for gain adjustment) Input pins for CH3 and CH4 (for gain adjustment) Power supply Level shift circuit reference voltage (V <sub>REF</sub> 1 buffer amplifier output*)
-			
3	V <sub>OUT</sub>		OP amp output
4	V <sub>IN</sub> -		OP amp inverted input
5 6	V <sub>IN</sub> + MUTE1	V <u>c</u> c	OP amp non-inverted input CH1, CH2 output ON/OFF
15	MUTE2	10 MUTE1, 2 (15) (15) (1) (1) (1) (1) (1) (1) (1) (1) (1) (1	CH3, CH4 output ON/OFF
21	V <sub>REF</sub> IN		Level shift circuit reference voltage input (V <sub>REF</sub> buffer amplifier input*)
23 24 26 27 28 29 31 32	V <sub>0</sub> 8 V <sub>0</sub> 7 V <sub>0</sub> 6 V <sub>0</sub> 5 V <sub>0</sub> 4 V <sub>0</sub> 3 V <sub>0</sub> 2 V <sub>0</sub> 1	(2) (24) V0 (3) (26) (23) (32) (27) (28) (1) (2) (17) (18) (1) (2) (17) (18) (1) (2) (35) (36) (1) (2) (35) (36) (36) (1) (2) (35) (36) (36) (1) (2) (37) (36) (36) (36) (36) (36) (36) (36) (36	CH4 inverted output (AMP8 output) CH4 non-inverted output (AMP7 output) CH3 inverted output (AMP6 output) CH3 non-inverted output (AMP5 output) CH2 inverted output (AMP4 output) CH2 non-inverted output (AMP3 output) CH1 inverted output (AMP2 output) CH1 non-inverted output (AMP1 output)
25	V <sub>S</sub> 2		CH3 (AMP5, AMP6), CH4 (AMP7, AMP8) output stage power supply
	V <sub>S</sub> 1		CH1 (AMP1, AMP2), CH2 (AMP3, AMP4) output stage power supply
30			
30 33	V <sub>SS</sub> -OUT		Output stage reference voltage (V <sub>SS</sub> 1/2: typ) (V <sub>REF</sub> 2 buffer amplifier output*)

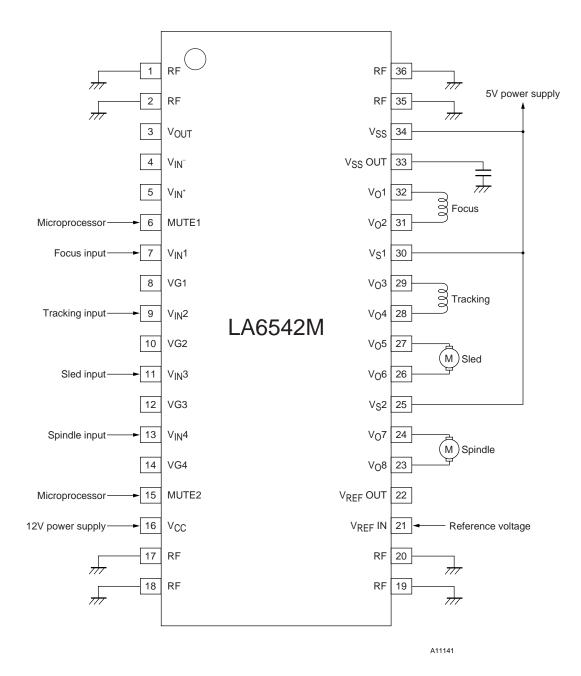
### **Block Diagram**



### System Diagram (relationship between power supply and MUTE)



### **Sample Application Circuit**



#### Gain Setting (input pins and adjustment pins)

A simplified diagram of  $V_{\mbox{\scriptsize IN}}$  and VG is shown below.

- 1) Consider an 11 k $\Omega$  (typ.) resistor inserted between V\_{IN} and VG.
- 2) When not the pin VG but the pin V<sub>IN</sub> is used alone, the BTL gain (between  $V_{O}^{+}$  and  $V_{O}^{-}$ ) is set to 6 dB (0 dB for AMP only). This also applies for the case when  $V_{IN}$  is not used and an 11 k $\Omega$  external resistor is connected to VG for input.

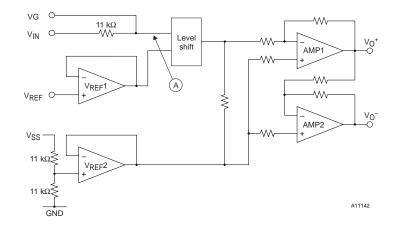
3) Gain is set by the input impedance as seen from point A.

When VG only is used and the external resistor is R, the BTL gain (between  $V_0^+$  and  $V_0^-$ ) is

20 log (11 k $\Omega/R$ ) + 6 dB.

When an 11 k $\Omega$  resistor is inserted between V<sub>IN</sub> and VG, and input is via V<sub>IN</sub>, the combined resistance Rz as seen from point A is Rz = 5.5 k $\Omega$ . Gain is

20 log (11 k $\Omega$  /5.5 k $\Omega$ ) + 6 dB = 12 dB.



#### **Offset Voltage**

This IC incorporates a level shifter circuit. The input references the  $V_{REF}$  to be applied, and references the voltage ( $V_{SS} - V_{BE}$  (0.7))/2V to be output.

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